

### 1. General description

The 74LVT125; 74LVTH125 is a quad buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). A HIGH on nOE causes the outputs to assume a high impedance OFF-state. Bus hold data inputs eliminate the need for external pull-up resistors to define unused inputs. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Quad bus interface
  - 3-state buffers
- Wide supply voltage range from 2.7 to 3.6 V
- BiCMOS high speed and output drive
- Output capability: +64 mA and -32 mA
- Direct interface with TTL levels
- Overvoltage tolerant inputs to 5.5 V
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Power-up 3-state
- IOFF circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 500 mA per JESD 78 Class II Level B
- Complies with JEDEC standard JESD8C (2.7 V to 3.6 V)
- ESD protection:
- HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
- CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to 85 °C

# 3. Ordering information

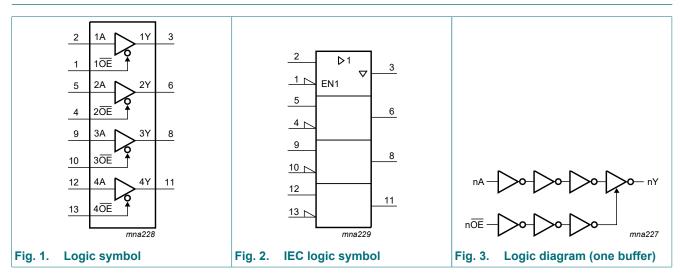
### Table 1. Ordering information

Type number	Package						
Temperature range Name		Name	Description	Version			
74LVT125D 74LVTH125D	-40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	<u>SOT108-1</u>			
74LVT125PW 74LVTH125PW	-40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	<u>SOT402-1</u>			
74LVT125BQ 74LVTH125BQ	-40 °C to +85 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	<u>SOT762-1</u>			

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3.3 V quad buffer; 3-state

### 4. Functional diagram

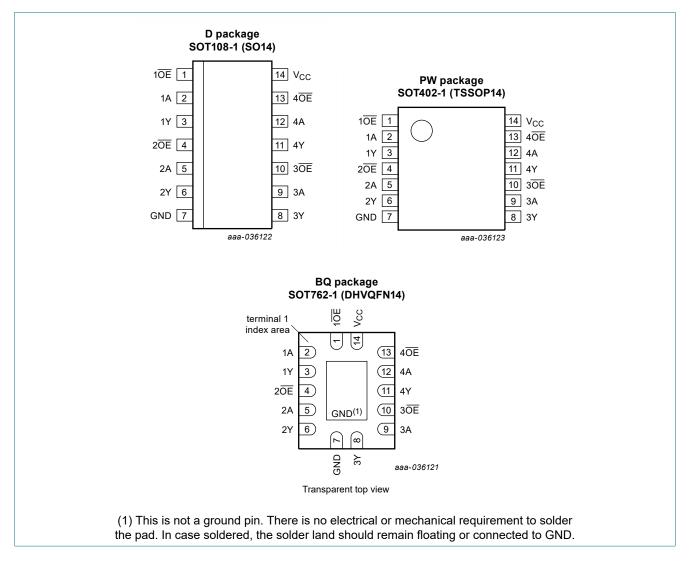


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### 5. Pinning information





74LVT\_LVTH125

Symbol	Pin	Description
1 <del>0E</del>	1	1 output enable input (active LOW)
1A	2	1 data input
1Y	3	1 data output
2 <del>0E</del>	4	2 output enable input (active LOW)
2A	5	2 data input
2Y	6	2 data output
GND	7	ground (0 V)
3Y	8	3 data output
3A	9	3 data input
3 <del>0E</del>	10	3 output enable input (active LOW)
4Y	11	4 data output
4A	12	4 data input
4 <del>0E</del>	13	4 output enable input (active LOW)
V <sub>CC</sub>	14	supply voltage

### 5.2. Pin description

# 6. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

	Input	Output
nOE	nA	nY
L	L	L
L	Н	Н
Н	x	Z

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	[1]	-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-	-50	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V		-	-50	mA
I <sub>O</sub>	output current	output in LOW-state		-	128	mA
		output in HIGH-state		-	-64	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
Tj	junction temperature		[2]	-	150	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CC</sub>	supply voltage		2.7	-	3.6	V
VI	input voltage		0	-	5.5	V
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		-	-	0.8	V
I <sub>OH</sub>	HIGH-level output current		-	-	-32	mA
I <sub>OL</sub>	LOW-level output current	none	-	-	32	mA
		current duty cycle ≤ 50 %;f ≥ 1 kHz	-	-	64	mA
Δt/ΔV	input transition rise and fall rate		0	-	10	ns/V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C

### 9. Static characteristics

### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter         Conditions		Min	Тур <mark>[1]</mark>	Max	Unit		
T <sub>amb</sub> = -4	T <sub>amb</sub> = -40 °C to +85 °C							
V <sub>IK</sub>	input clamping voltage	I <sub>IK</sub> = -18 mA; V <sub>CC</sub> = 2.7 V	-	-0.9	-1.2	V		
V <sub>OH</sub>	HIGH-level output voltage	$I_{OH}$ = -100 µA; $V_{CC}$ = 2.7 V to 3.6 V	V <sub>CC</sub> - 0.2	V <sub>CC</sub> - 0.1	-	V		
		I <sub>OH</sub> = -8 mA; V <sub>CC</sub> = 2.7 V	2.4	2.5	-	V		
		I <sub>OH</sub> = -32 mA; V <sub>CC</sub> = 3.0 V	2.0	2.2	-	V		

### 3.3 V quad buffer; 3-state

Symbol	Parameter	Conditions		Min	Typ [1]	Мах	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>CC</sub> = 2.7 V					
		I <sub>OL</sub> = 100 μA		-	0.1	0.2	V
		I <sub>OL</sub> = 24 mA		-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V					
		I <sub>OL</sub> = 16 mA		-	0.25	0.4	V
		I <sub>OL</sub> = 32 mA		-	0.3	0.5	V
		I <sub>OL</sub> = 64 mA		-	0.4	0.55	V
l <sub>l</sub>	input leakage current	all input pins					
		V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V		-	1	10	μA
		control pins					
		$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND		-	±0.1	±1	μA
		data pins	[2]				
		$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = \text{V}_{CC}$		-	0.1	1	μA
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V		-	-1	-5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; \text{ V}_{I} \text{ or } \text{ V}_{O} = 0 \text{ V to } 4.5 \text{ V}$		-	1	±100	μA
I <sub>BHL</sub>	bus hold LOW current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 0.8 V	[3]	75	150	-	μA
I <sub>BHH</sub>	bus hold HIGH current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 2.0 V		-	-150	-75	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = 0 \text{ V} \text{ to } 3.6 \text{ V}$		500	-	-	μA
I <sub>BHHO</sub>	bus hold HIGH overdrive current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = 0 \text{ V} \text{ to } 3.6 \text{ V}$		-	-	-500	μA
I <sub>LO</sub>	output leakage current	output in HIGH-state when $V_O > V_{CC}$ ; $V_O = 5.5 V$ ; $V_{CC} = 3.0 V$		-	60	125	μA
I <sub>O(pu/pd)</sub>	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V to } V_{CC};$ V <sub>I</sub> = GND or V <sub>CC</sub> ; nOE = don't care	[4]	-	±1	±100	μA
I <sub>OZ</sub>	OFF-state output current	$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{IH}$ or $V_{IL}$					
		output HIGH: V <sub>O</sub> = 3.0 V		-	1	5	μA
		output LOW: V <sub>O</sub> = 0.5 V		-	-1	-5	μA
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A					
		outputs HIGH		-	0.13	0.19	mA
		outputs LOW		-	2	7	mA
		outputs disabled	[5]	-	0.13	0.19	mA
∆I <sub>CC</sub>	additional supply current	per input pin; $V_{CC}$ = 3 V to 3.6 V; [6] one input at $V_{CC}$ - 0.6 V and other inputs at $V_{CC}$ or GND		-	0.1	0.2	mA
CI	input capacitance	V <sub>1</sub> = 0 V or 3.0 V		-	4	-	pF
Co	output capacitance	outputs disabled; $V_0 = 0 V$ or 3.0 V		-	8	-	pF

[1] Typical values are measured at V\_{CC} = 3.3 V and T<sub>amb</sub> = 25 °C.

[2] Unused pins at  $V_{CC}$  or GND.

[3] This is the bus hold overdrive current required to force the input to the opposite logic state.

[4] This parameter is valid for any  $V_{CC}$  between 0 V and 1.2 V with a transition time of up to 10 ms.

From V<sub>CC</sub> = 1.2 V to V<sub>CC</sub> = 3.0 V to 3.6 V a transition time of 100 µs is permitted. This parameter is valid for T<sub>amb</sub> = 25 °C only.

[5]  $I_{CC}$  is measured with outputs pulled to  $V_{CC}$  or GND.

<sup>[6]</sup> This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

# **10.** Dynamic characteristics

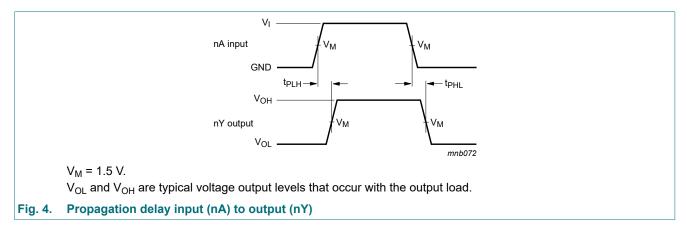
### Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

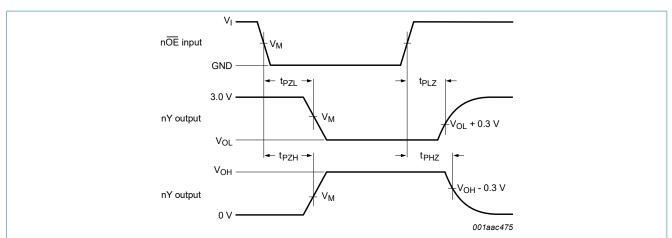
Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C			11		-1
t <sub>PLH</sub>	LOW to HIGH propagation delay	nAn to nY; see <u>Fig. 4</u>				
		V <sub>CC</sub> = 2.7 V	-	-	4.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.7	4.0	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nAn to nY; see <u>Fig. 4</u>				
		V <sub>CC</sub> = 2.7 V	-	-	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	2.9	3.9	ns
t <sub>PZH</sub> OF	OFF-state to HIGH propagation delay	nOE to nY; see Fig. 5				
		V <sub>CC</sub> = 2.7 V	-	-	6.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.0	3.4	4.7	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	nOE to nY; see Fig. 5				
		V <sub>CC</sub> = 2.7 V	-	-	6.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.1	3.4	4.7	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	nOE to nY; see <u>Fig. 5</u>				
		V <sub>CC</sub> = 2.7 V	-	-	5.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	3.7	5.1	ns
t <sub>PLZ</sub>	LOW to OFF-state propagation delay	nOE to nY; see Fig. 5				
		V <sub>CC</sub> = 2.7 V	-	-	4.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.3	2.6	4.5	ns

[1] Typical values are at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

### 10.1. Waveforms and test circuit



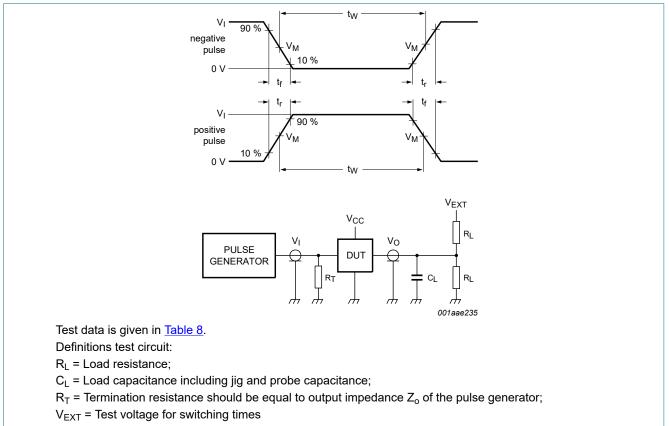
### 3.3 V quad buffer; 3-state



V<sub>M</sub> = 1.5 V.

 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

### Fig. 5. Enable and disable times of 3-state outputs



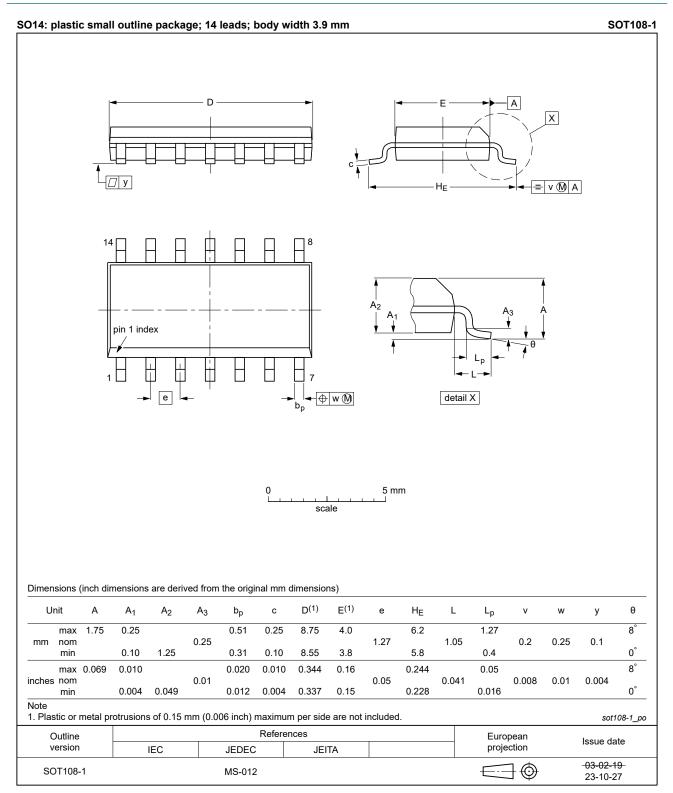
### Fig. 6. Test circuit for measuring switching times

Table 8. Test data								
Input			Load	Load		V <sub>EXT</sub>		
VI	fi	t <sub>w</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHZ</sub> , t <sub>PZH</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V	open

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3.3 V quad buffer; 3-state

## 11. Package outline



### Fig. 7. Package outline SOT108-1 (SO14)

### 3.3 V quad buffer; 3-state

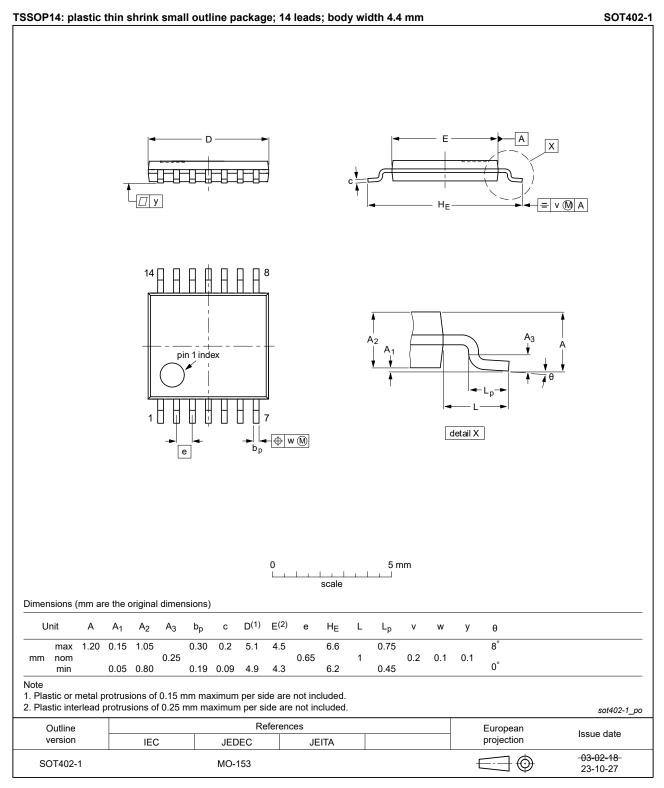


Fig. 8. Package outline SOT402-1 (TSSOP14)

### 3.3 V quad buffer; 3-state

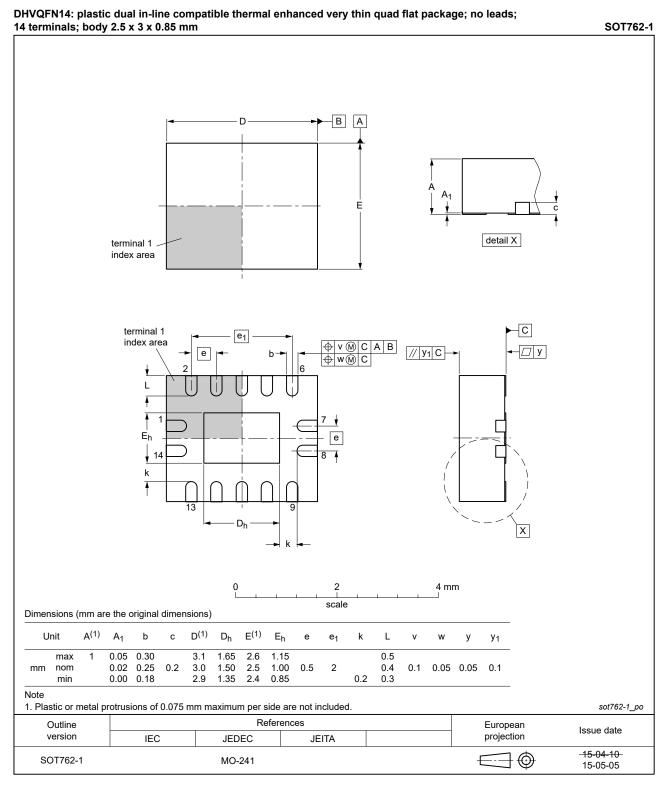


Fig. 9. Package outline SOT762-1 (DHVQFN14)

# 12. Abbreviations

Acronym	Description	
ANSI	American National Standards Institute	
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor	
CDM	Charged Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
ESDA	ElectroStatic Discharge Association	
HBM	Human Body Model	
JEDEC	Joint Electron Device Engineering Council	
TTL	Transistor-Transistor Logic	

# 13. Revision history

Table 10. Revision histor	Release date	Data sheet status	Change notice	Supersedes		
74LVT_LVTH125 v.9	20240530	Product data sheet	-	74LVT_LVTH125 v.8		
Modifications:	MO-153.	8: Aligned SO and TSSO		drawings to JEDEC MS-012 and atest JEDEC standard.		
74LVT_LVTH125 v.8	20210818	Product data sheet	-	74LVT_LVTH125 v.7		
Modifications:	guidelines c Legal texts Type number <u>Section 1</u> at	<ul> <li>Type numbers 74LVT125DB and 74LVTH125DB (SOT337-1/SSOP14) removed.</li> </ul>				
74LVT_LVTH125 v.7	20160531	Product data sheet	-	74LVT125 v.6		
Modifications:	guidelines o	of this data sheet has been for this data sheet has been for NXP Semiconductors. have been adapted to the	-	mply with the new identity me where appropriate.		
74LVT_LVTH125 v.6	20060306	Product data sheet	-	74LVT125 v.5		
Modifications:	• <u>Section 3</u> : A 74LVTH125	•	/TH125D, 74LVTH	125DB, 74LVTH125PW and		
74LVT125 v.5	20050210	Product data sheet	-	74LVT125 v.4		
74LVT125 v.4	20050207	Product data sheet	-	74LVT125 v.3		
74LVT125 v.3	20040624	Product data sheet	-	74LVT125 v.2		
74LVT125 v.2	19980219	Product specification	-	74LVT125 v.1		
74LVT125 v.1	-	-	-	-		

# 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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